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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS



Product specification IC24 Data Handbook 1998 Jun 29



HILIPS

Philips Semiconductors

### 74ALVCH162245

#### **FEATURES**

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTE<sup>TM</sup> flow-through standard pin-out architecture
- Low inductance multiple V<sub>CC</sub> and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Bus hold on all data inputs
- Integrated 30Ω termination resistor

#### DESCRIPTION

The 74ALVCH162245 is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions.

The 74ALVCH162245 features two output enable (n $\overline{\text{OE}}$ ) inputs for easy cascading and two send/receive (nDIR) inputs for direction control. nOE controls the outputs so that the buses are effectively isolated. This device can be used as two 8-bit transceivers or one 16-bit transceiver.

The 74ALVCH162245 is designed with  $30\Omega$  series resistors in both HIGH and LOW output states.

The 74ALVCH162245 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

### **PIN CONFIGURATION**

	1DIR 1	48	1 <del>0E</del>
	1B0 2	47	1A0
	1B1 3	46	1A1
	GND 4	45	GND
	1B2 5	44	1A2
	1B3 6	43	1A3
	V <sub>CC1</sub> 7	42	V <sub>CC2</sub>
	1B4 8	41	1A4
	1B5 9	40	1A5
	GND 10	39	GND
	1B6 11	38	1A6
	1B7 12	37	1A7
	2B0 13	36	2A0
	2B1 14	35	2A1
	GND 15	34	GND
	2B2 16	33	2A2
	2B3 17	32	2A3
	V <sub>CC1</sub> [18	31	V <sub>CC2</sub>
	2B4 [19	30	2A4
	2B5 20	29	2A5
	GND 21	28	GND
	2B6 22	27	2A6
	2B7 23	26	2A7
	2DIR 24	25	2 <del>0E</del>
L		SW00198	

#### QUICK REFERENCE DATA

$GND = 0V; T_{amb}$	= $25^{\circ}$ C; $t_r = t_f \le 2.5$ ns				
SYMBOL	PARAMETER	CONDITION	NS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to Bn; Bn to An	$V_{CC} = 2.5V, C_L = 30pF$ $V_{CC} = 3.3V, C_L = 50pF$		2.4	ns
Cl	Input capacitance			4.0	pF
C <sub>I/O</sub>	Input/output capacitance			8.0	pF
C	Power dissipation capacitance per buffer	$V_{I} = GND$ to $V_{CC}^{1}$	Outputs enabled	27	pF
C <sub>PD</sub>	Power dissipation capacitance per buller	VI = GIND to VCC.	Outputs disabled	4	pF

NOTES:

1.  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where: } f_{i} = \text{input frequency in MHz; } C_{L} = \text{output load capacitance in pF;}$  $f_{o} = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) = \text{sum of the outputs.}$ 

#### ORDERING INFORMATION

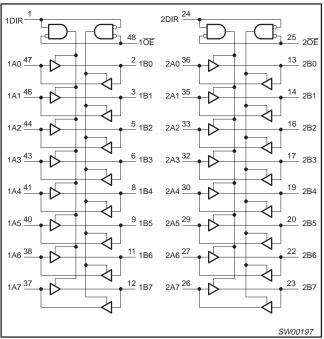
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVCH162245 DL	ACH162245 DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVCH162245 DGG	ACH162245 DGG	SOT362-1

### 74ALVCH162245

### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1DIR	Direction control
2, 3, 5, 6, 8, 9, 11, 12	1B0 to 1B7	Data inputs/outputs
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V <sub>CC</sub>	Positive supply voltage
13, 14, 16, 17, 19, 20, 22, 23	2B0 to 2B7	Data inputs/outputs
24	2DIR	Direction control
25	2 <del>0E</del>	Output enable input (active LOW)
36, 35, 33, 32, 30, 29, 27, 26	2A0 to 2A7	Data inputs/outputs
47, 46, 44, 43, 41, 40, 38, 37	1A0 to 1A7	Data inputs/outputs
48	1 <del>0E</del>	Output enable input (active LOW)

#### LOGIC SYMBOL



### **FUNCTION TABLE**

INPU	JTS	INPUTS/OUTPUT		
nOE	nDIR	nAn	nBn	
L	L	A = B	inputs	
L	Н	inputs	B = A	
Н	Х	Z	Z	

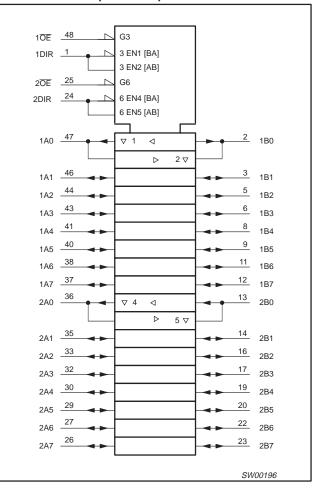
H = HIGH voltage level

L = LOW voltage level

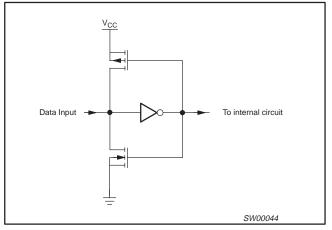
X = don't care

Z = high impedance OFF-state

### LOGIC SYMBOL (IEEE/IEC)



### **BUS HOLD CIRCUIT**



## 74ALVCH162245

SYMBOL	PARAMETER	CONDITIONS	LIM	ITS	UNIT
STWBOL	PARAIMETER	CONDITIONS	MIN	MAX	UNIT
	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
V <sub>CC</sub>	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V
VI	DC Input voltage range		0	V <sub>CC</sub>	V
Vo	DC output voltage range		0	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating free-air temperature range		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	V <sub>CC</sub> = 2.3 to 3.0V V <sub>CC</sub> = 3.0 to 3.6V	0 0	20 10	ns/V

### **RECOMMENDED OPERATING CONDITIONS**

#### **ABSOLUTE MAXIMUM RATINGS**

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
V	DC input voltage	For data inputs with bus hold <sup>1</sup>	–0.5 to V <sub>CC</sub> +0.5	v
VI	DC input voltage	For control pins <sup>1</sup>	-0.5 to +4.6	v
I <sub>OK</sub>	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
V <sub>O</sub>	DC output voltage	Note 1	–0.5 to V <sub>CC</sub> +0.5	V
Ι <sub>Ο</sub>	DC output source or sink current	$V_{O} = 0$ to $V_{CC}$	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)		For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 74ALVCH162245

#### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp :	UNIT		
			MIN	TYP <sup>1</sup>	MAX	1
		V <sub>CC</sub> = 2.3 to 2.7V	1.7	1.2		
V <sub>IH</sub>	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0	1.5		V
N		V <sub>CC</sub> = 2.3 to 2.7V		1.2	0.7	v
V <sub>IL</sub>	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V		1.5	0.8	1
		$V_{CC}$ = 2.3 to 3.6V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -100 $\mu$ A	V <sub>CC</sub> -0.2	V <sub>CC</sub>		
		$V_{CC}$ = 2.3V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -4mA	V <sub>CC</sub> -0.4	V <sub>CC</sub> -0.11		1
		$V_{CC}$ = 2.3V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -6mA	V <sub>CC</sub> -0.6	V <sub>CC</sub> _0.17		1
V <sub>OH</sub>	HIGH level output voltage	$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -4mA	V <sub>CC</sub> -0.5	V <sub>CC</sub> -0.09		V
		$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = -8mA	V <sub>CC</sub> -0.7	V <sub>CC</sub> -0.19		1
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -6mA$	V <sub>CC</sub> -0.6	V <sub>CC</sub> _0.13		1
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -12mA$	V <sub>CC</sub> -1.0	V <sub>CC</sub> -0.27		1
		$V_{CC}$ = 2.3 to 3.6V; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 100\mu A$		GND	0.20	
		$V_{CC}$ = 2.3V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 4mA		0.07	0.40	1
		$V_{CC}$ = 2.3V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 6mA		0.11	0.55	1
V <sub>OL</sub>	LOW level output voltage	$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 4mA		0.06	0.40	V
		$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 8mA		0.13	0.60	1
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 6mA$		0.09	0.55	1
		$V_{CC} = 3.0V$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 12mA$		0.19	0.80	1
lı	Input leakage current per data pin with bus hold	$V_{CC} = 2.3$ to 3.6V; $V_I = V_{CC}$ or GND		0.1	5	μA
I <sub>OZ</sub>	3-State output OFF-state current	$V_{CC}$ = 2.3 to 3.6V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $V_O$ = $V_{CC}$ or GND		0.1	10	μΑ
I <sub>CC</sub>	Quiescent supply current	$V_{CC}$ = 2.3 to 3.6V; $V_{I}$ = $V_{CC}$ or GND; $I_{O}$ = 0		0.2	40	μA
$\Delta I_{CC}$	Additional quiescent supply current given per data I/O pin with bus hold	$V_{CC} = 2.3V$ to 3.6V; $V_I = V_{CC} - 0.6V$ ; $I_O = 0$		150	750	μΑ
1 2		$V_{CC} = 2.3V; V_{I} = 0.7V$	45	-		
I <sub>BHL</sub> <sup>2</sup>	Bus hold LOW sustaining current	$V_{CC} = 3.0V; V_1 = 0.8V$	75	150		μA
1 2		V <sub>CC</sub> = 2.3V; V <sub>I</sub> = 1.7V	-45			
I <sub>BHH</sub> <sup>2</sup>	Bus hold HIGH sustaining current	$V_{CC} = 3.0V; V_1 = 2.0V$	-75	-175		μA
I <sub>BHLO</sub> 2	Bus hold LOW overdrive current	V <sub>CC</sub> = 3.6V	500			μA
I <sub>BHHO</sub> <sup>2</sup>	Bus hold HIGH overdrive current	V <sub>CC</sub> = 3.6V	-500			μA

NOTES:

1. All typical values are at  $T_{amb} = 25^{\circ}C$ . 2. Valid for data inputs of bus hold parts.

## 74ALVCH162245

## AC CHARACTERISTICS FOR V<sub>CC</sub> = 2.3V TO 2.7V RANGE GND = 0V; t<sub>f</sub> = t<sub>f</sub> $\leq$ 2.0ns; C<sub>L</sub> = 30pF

				LIMITS		
SYMBOL	PARAMETER	WAVEFORM	V	<sub>CC</sub> = 2.3 to 2.7	'V	UNIT
			MIN	TYP <sup>1, 2</sup>	MAX	
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nAn to nBn; nBn to nAn	1, 3	1.0	2.5	4.9	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-State output enable time nOE to nAn; nOE to nBn	2, 3	1.0	2.9	6.8	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-State output disable time nOE to nAn; nOE to nBn	2, 3	1.0	3.0	6.3	ns

NOTES:

1. All typical values are measured  $T_{amb} = 25^{\circ}C$ .

2. Typical value is measured at  $V_{CC}$  = 2.5V

## AC CHARACTERISTICS FOR $V_{CC}$ = 3.0V TO 3.6V RANGE AND $V_{CC}$ = 2.7V GND = 0V; $t_r = t_f \le 2.5$ ns; $C_L = 50$ pF

					LIM	ITS			
SYMBOL	PARAMETER	WAVEFORM	Vc	$c = 3.3 \pm 0.2$	.3V	\	/ <sub>CC</sub> = 2.7\	/	UNIT
			MIN	TYP <sup>1, 2</sup>	MAX	MIN	TYP <sup>1</sup>	MAX	
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nAn to nBn; nBn to nAn	1, 3	1.0	2.4	4.2	1.0	2.7	4.7	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-State output enable time nOE to nAn; nOE to nBn	2, 3	1.0	3.0	5.6	1.0	3.9	6.7	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-State output disable time nOE to nAn; nOE to nBn	2, 3	1.0	2.6	5.5	1.0	2.9	5.7	ns

NOTES:

1. All typical values are measured  $T_{amb}$  = 25°C.

2. Typical value is measured at  $V_{CC}$  = 3.3V

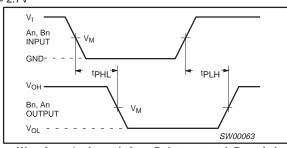
## 74ALVCH162245

## AC WAVEFORMS FOR V<sub>CC</sub> = 2.3V TO 2.7V AND V<sub>CC</sub> < 2.3V RANGE

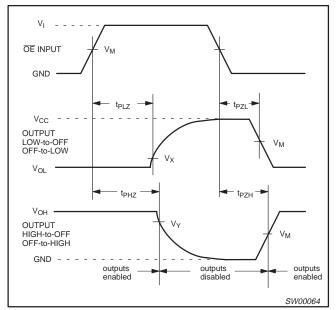
 $\label{eq:VM} \begin{array}{l} V_M = 0.5 \; V_{CC} \\ V_X = V_{OL} + 0.15 V \\ V_Y = V_{OH} - 0.15 V \\ V_{OL} \; \text{and} \; V_{OH} \; \text{are the typical output voltage drop that occur with the output load.} \\ \end{array}$ 

## AC WAVEFORMS FOR V<sub>CC</sub> = 3.0V TO 3.6V AND V<sub>CC</sub> = 2.7V RANGE

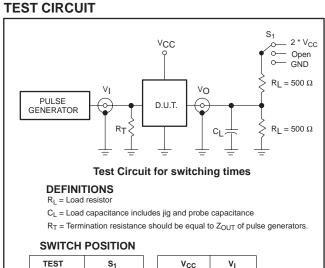
 $V_{M}^{V} = 1.5 \text{ V}$   $V_{X} = V_{OL} + 0.3 \text{ V}$   $V_{Y} = V_{OH} - 0.3 \text{ V}$   $V_{OL} \text{ and } V_{OH} \text{ are the typical output voltage drop that occur with the output load.}$   $V_{I}^{V} = 2.7 \text{ V}$ 

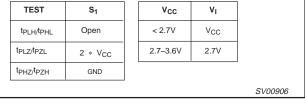


Waveform 1. Input (nAn, nBn) to output (nBn, nAn) propagation delay times



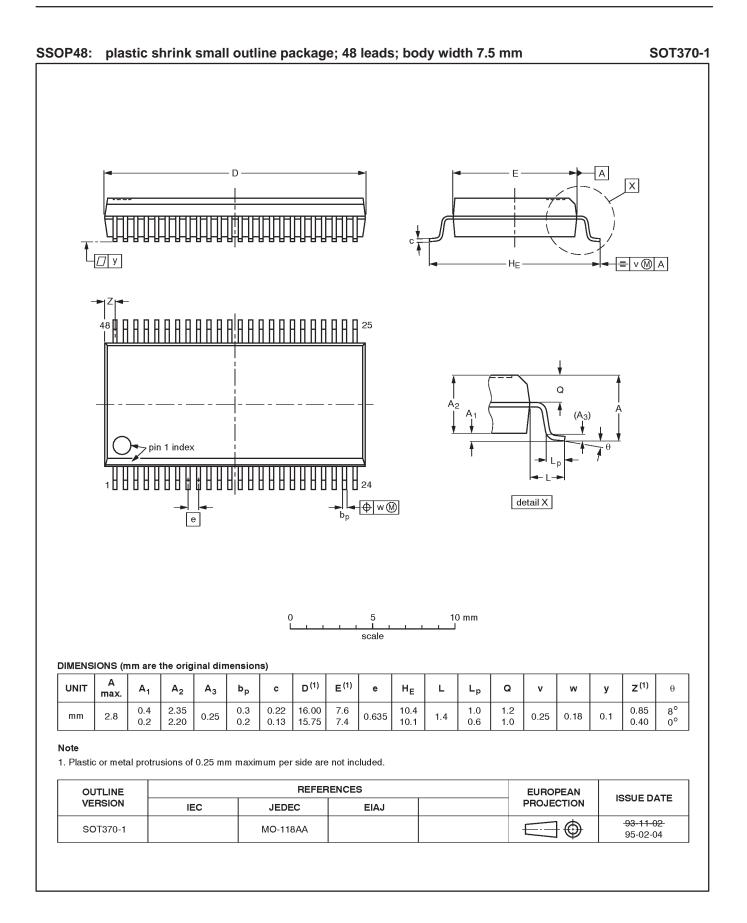
Waveform 2. 3-State enable and disable times



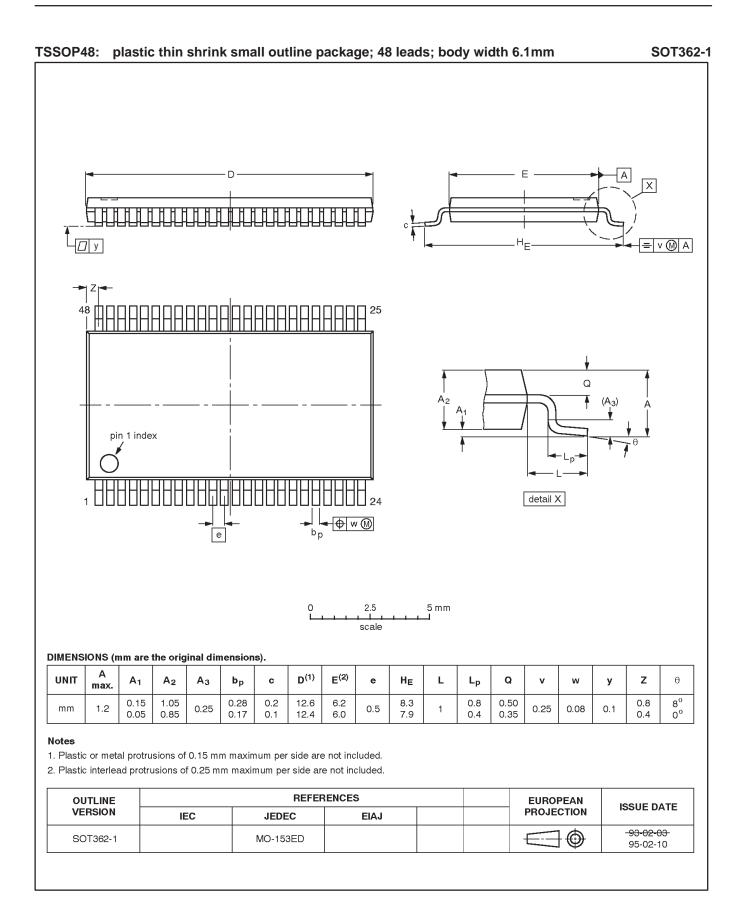


Waveform 3. Load circuitry for switching times

### 74ALVCH162245



## 74ALVCH162245



## 74ALVCH162245

NOTES

## 74ALVCH162245

#### Data sheet status

Data sheet status	Product status	Definition <sup>[1]</sup>
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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